



Radiation Hardness Studies of Polycrystalline & Single-crystal Chemical Vapor Deposition Diamond for High Luminosity Tracking Detectors

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Outline of the Talk

- ❖ Introduction
- ❖ Radiation Hardness Studies with Trackers
- ❖ Diamond Pixel Modules
- ❖ Plans
- ❖ Summary



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◇ Spokespersons

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22 Institutes



Motivation

- ❖ Radiation hardness (no frequent replacements)
- ❖ Low dielectric constant → low capacitance
- ❖ Low leakage current → low readout noise
- ❖ Good insulating properties → large active area
- ❖ Room temperature operation, Fast signal collection time → no cooling
- ❖ Disadvantage: Smaller signal

Priorities (ATU-RD-MN-0012):

- ❖ Radiation hardness tests of the highest quality pCVD and scCVD diamond
- ❖ Beam tests results to characterize quality
- ❖ Development of new manufacturers
- ❖ Module preparation

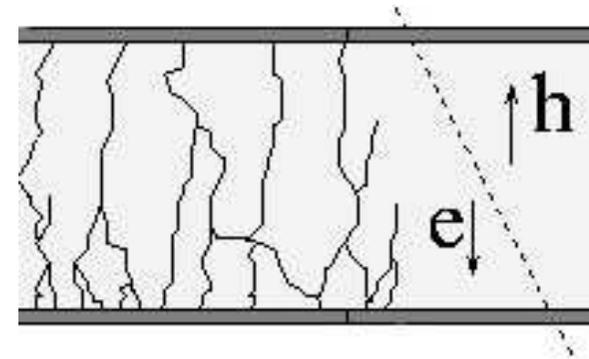
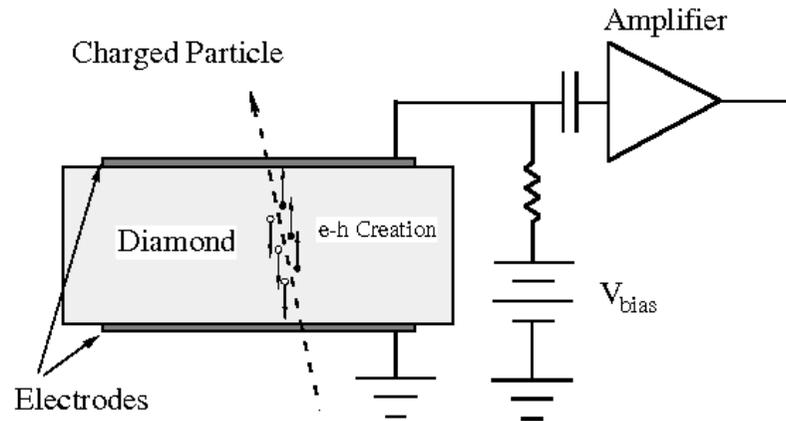
These points will be addressed in this talk.

- ❖ See also: F. Hügging poster at this meeting
- ❖ Reference → <http://rd42.web.cern.ch/RD42>



Characterization of Diamond:

Signal formation



❖ $Q = \frac{d}{t} Q_0$ where d = collection distance = distance e-h pair move apart

❖ $d = (\mu_e \tau_e + \mu_h \tau_h) E$

❖ $d = \mu E \tau$

with $\mu = \mu_e + \mu_h$
 and $\tau = \frac{\mu_e \tau_e + \mu_h \tau_h}{\mu_e + \mu_h}$

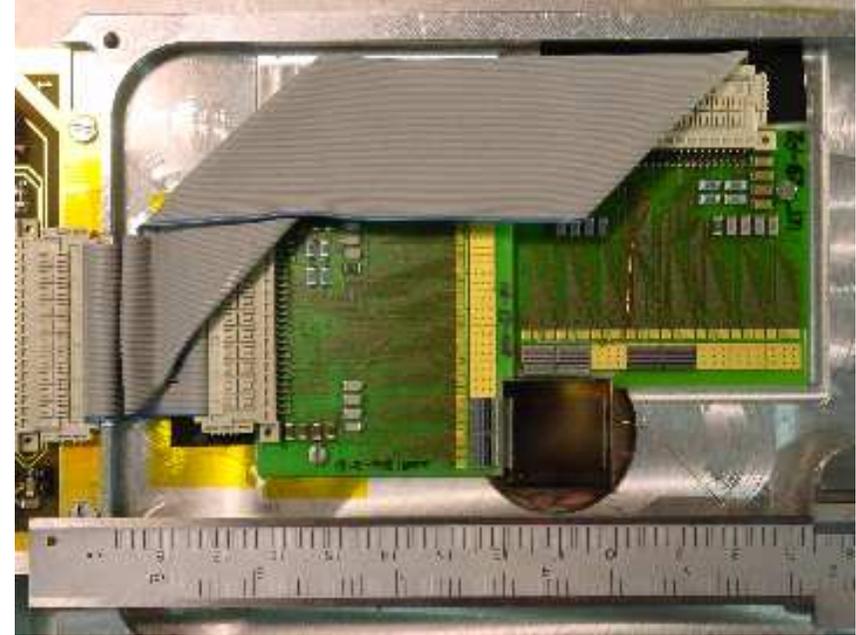
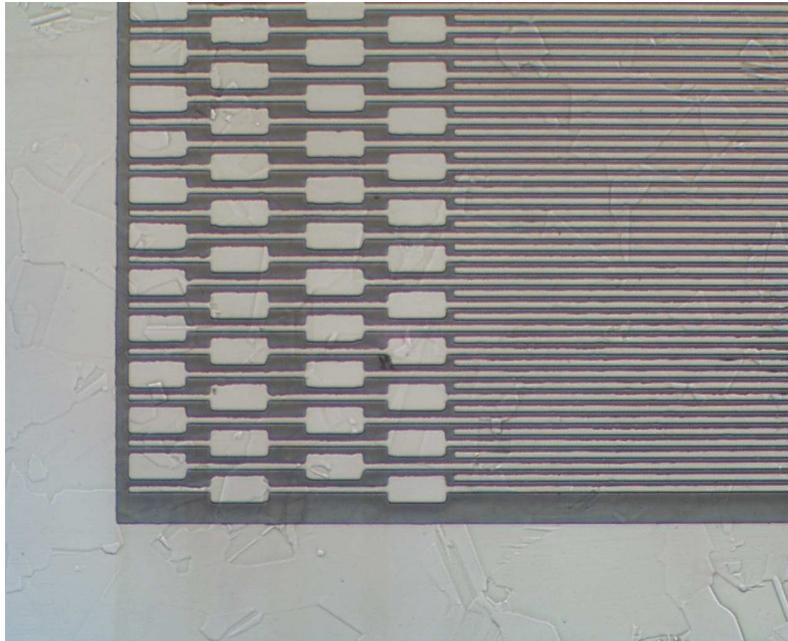


Radiation Hardness

- binding energy
- displacement energy
- elastic, inelastic, total cross section



pCVD Diamond Trackers:



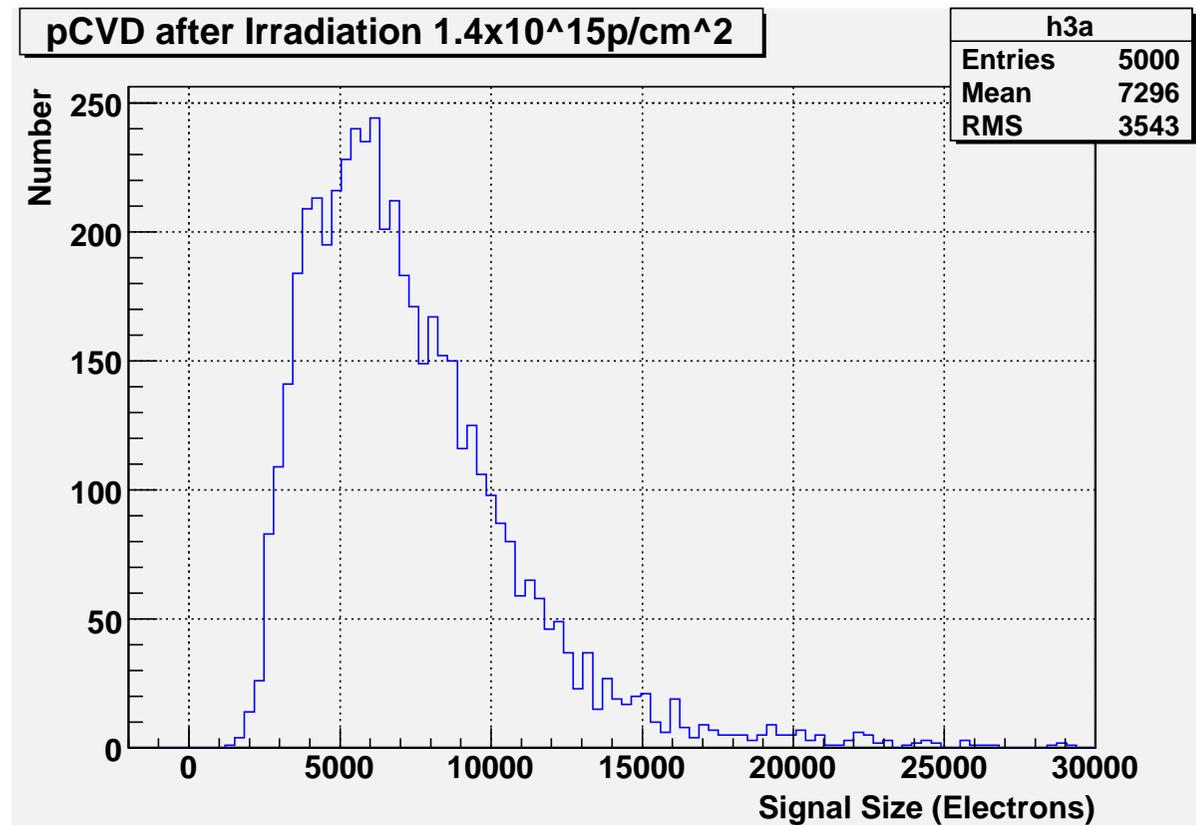
- ❖ Patterning the diamond → pads, strips, pixels!
- ❖ Successfully made double-sided devices; could be made basically edgeless.
- ❖ Use trackers (strip and pixel) in radiation studies - charge and position.



pCVD Diamond After Irradiation



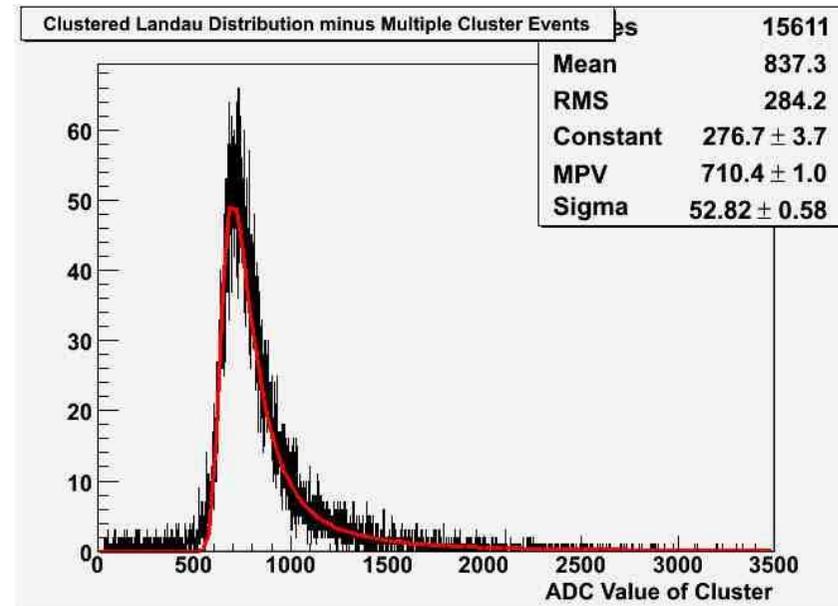
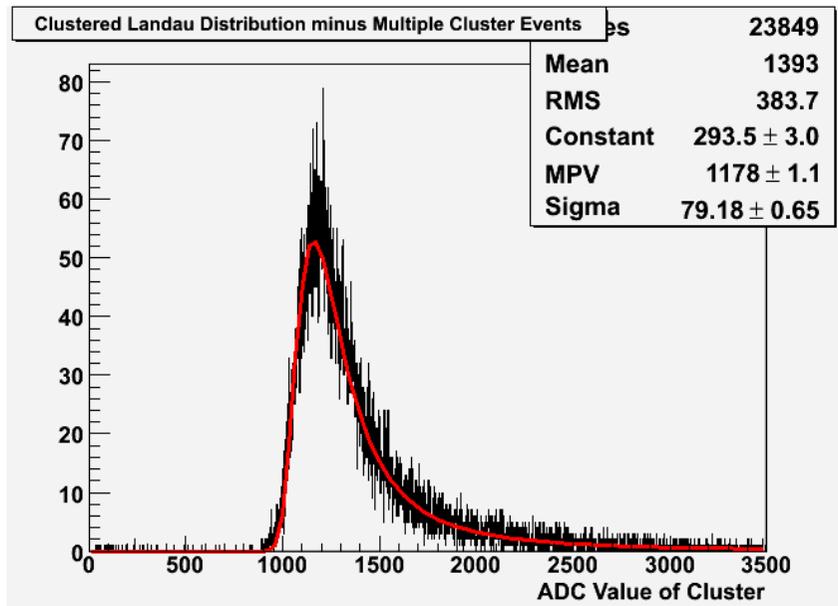
Polycrystalline CVD (pCVD) Diamond irradiated to $1.4 \times 10^{15} \text{ p/cm}^2$



- ❖ Application is pixel detectors
- ❖ In-time thresholds are \sim threshold ($1450e$) plus overdrive ($800e$)
- ❖ PH distributions after $1.4 \times 10^{15} \text{ p/cm}^2 \rightarrow \epsilon > 99\%$.



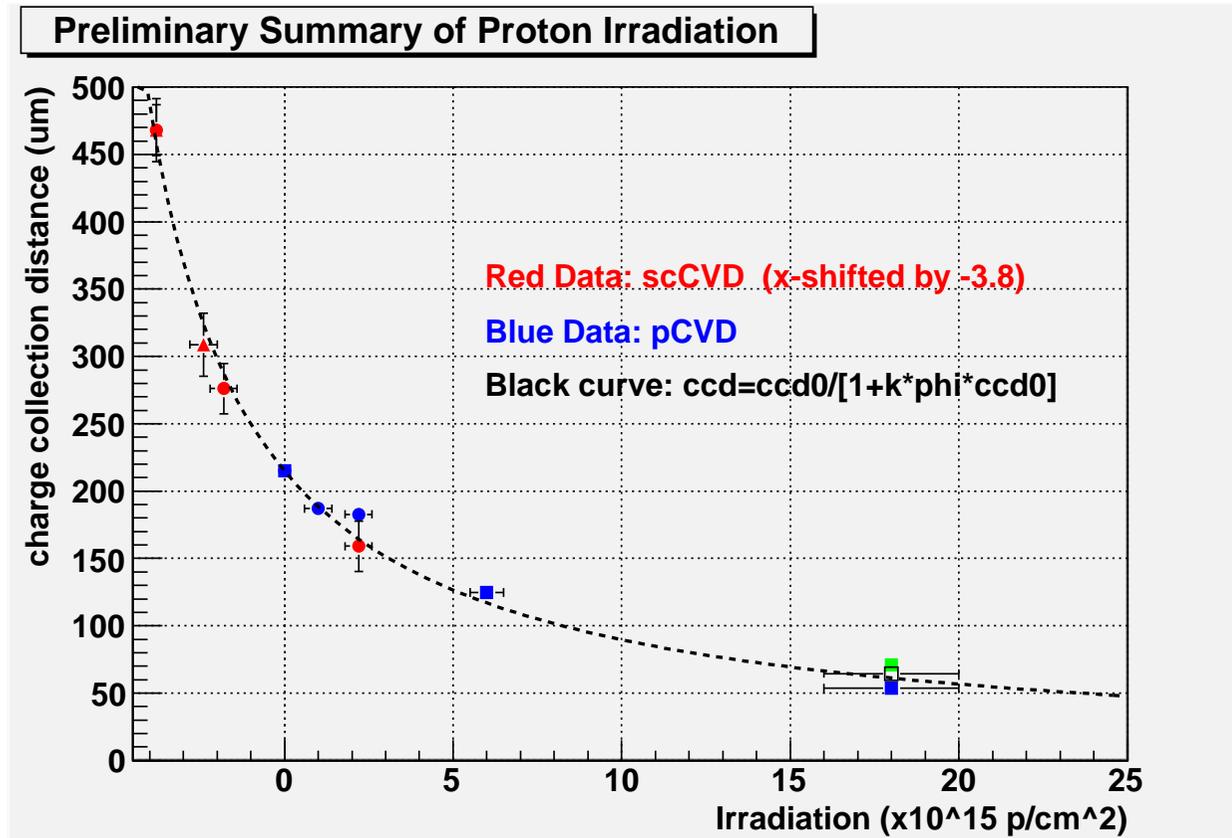
Single Crystal CVD (scCVD) Diamond irradiated to $1.5 \times 10^{15} \text{ p/cm}^2$



- ❖ PH distributions look narrow before and after irradiation
- ❖ In-time thresholds are $\sim \text{threshold}(1500e) + \text{overdrive}(800e)$
- ❖ PH distributions after $1.5 \times 10^{15} \text{ p/cm}^2 \rightarrow \epsilon > 99\%$.



Proton Irradiation Summary - preliminary:



Preliminary summary of proton irradiation results for pCVD (blue) and scCVD diamond (red) at $E=1\text{V}/\mu\text{m}$ up to $1.8 \times 10^{16} \text{ p/cm}^2$ ($\sim 500\text{Mrad}$).
pCVD and scCVD diamond follow the same damage curve:
 $1/\text{ccd} = 1/\text{ccd}_0 + k \phi$.



CVD Diamond Material Status

- collection distance
- polycrystalline, single crystal
- new manufacturers

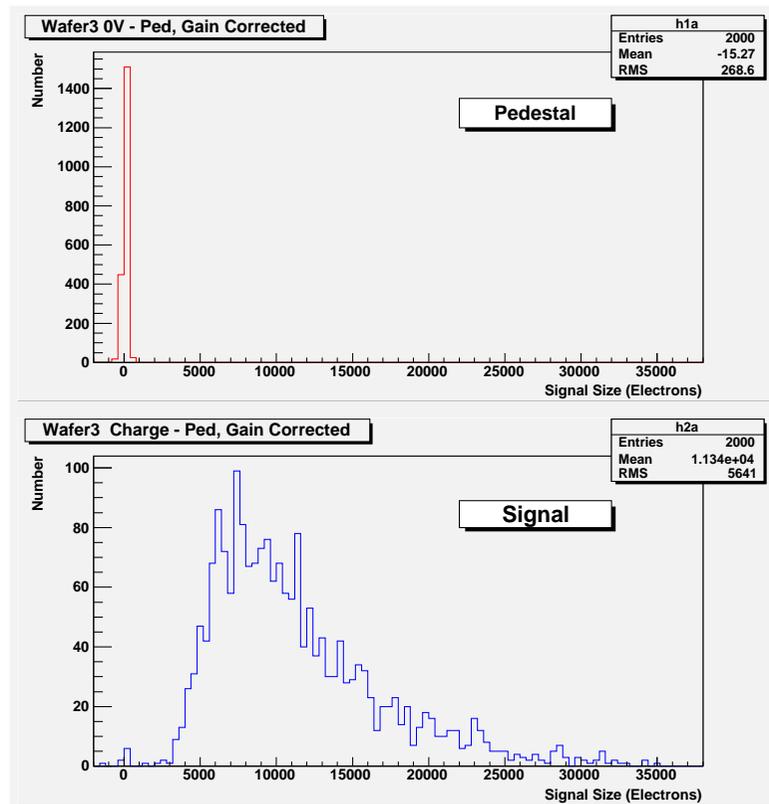


Material Status - pCVD Diamond



pCVD Material: pCVD Diamond Measured with a ^{90}Sr Source

- ◆ Contacts on both sides - structures from μm to cm
- ◆ Usually operate at $E=1\text{-}2\text{V}/\mu\text{m}$
- ◆ Test Procedure: dot \rightarrow strip \rightarrow pixel on same diamond!



- ◆ $Q_{MP} = 8500\text{-}9000e$
- ◆ Mean Charge = $11300e$

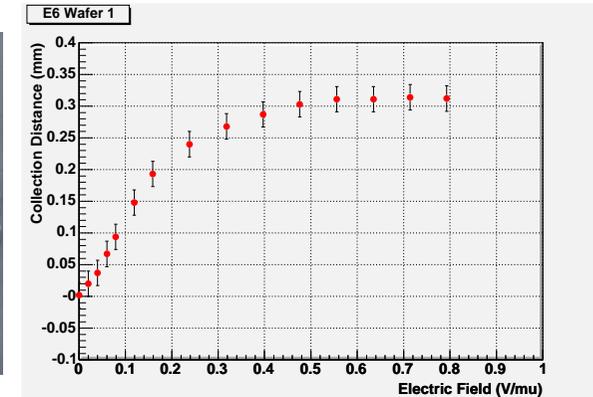
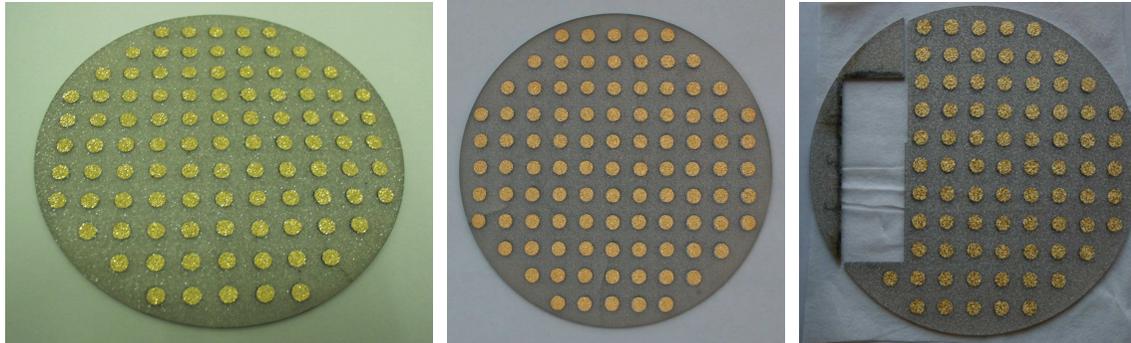
- ◆ Source data well separated from 0
- ◆ Collection Distance now $\approx 300\mu\text{m}$
- ◆ Most Probable Charge now $\approx 9000e$
- ◆ 99% of PH distribution above $4000e$
- ◆ $\text{FWHM}/\text{MP} \approx 0.95$ — Si has ≈ 0.5
- ◆ Four wafers grown with this quality; two in progress



Material Status - pCVD Diamond



Recent Polycrystalline CVD Diamond



Left: Recent pCVD wafers ready for test - Cr/Au dots are 1 cm apart
Right: Collection distance from a dot in the pCVD wafer

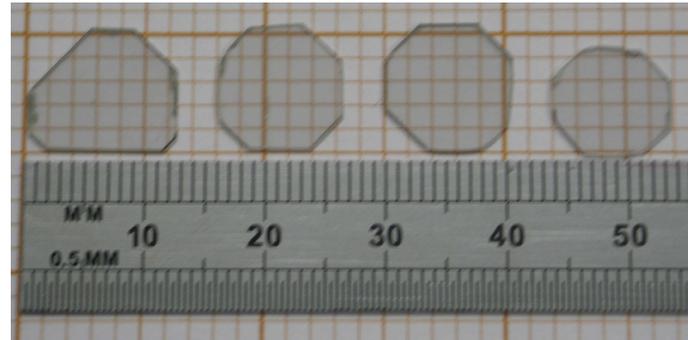
pCVD diamond wafers can be grown >12 cm diameter, >2 mm thickness.
Wafer collection distance now typically 250 μ m (edge) to 310 μ m (center).



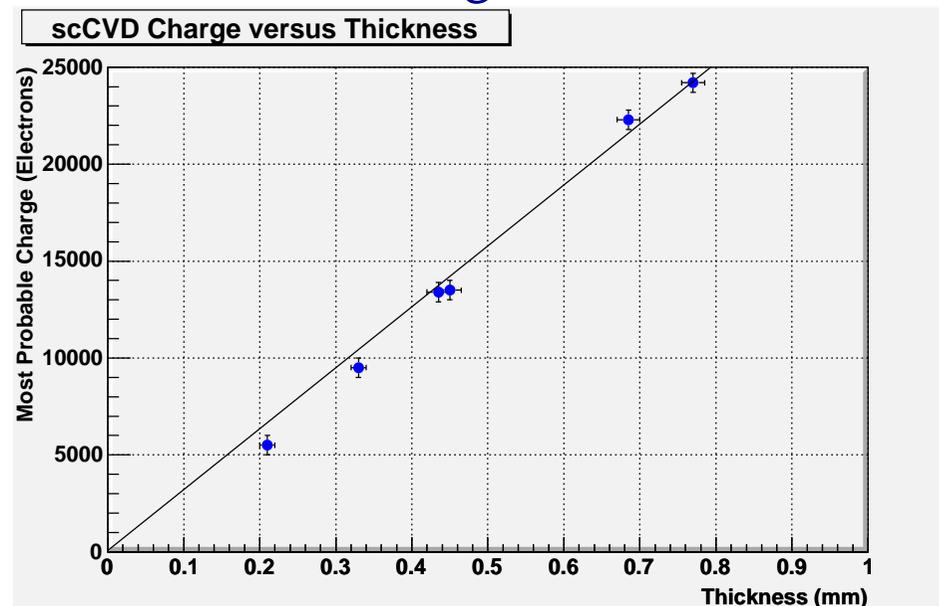
Material Status - Single Crystal CVD Diamond



Recent Single Crystal CVD Diamond



scCVD Diamond Most Probable Charge versus Thickness



◆ High quality scCVD diamond can collect full charge for thickness $880\mu\text{m}$

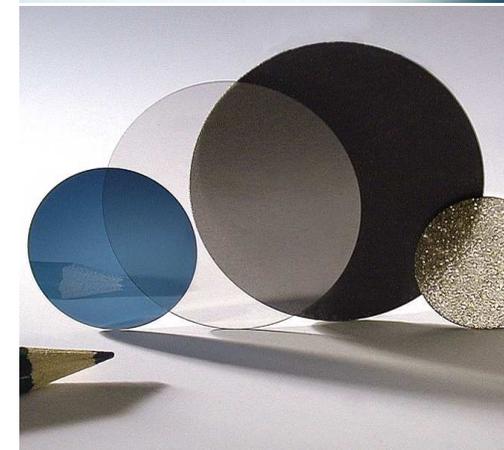
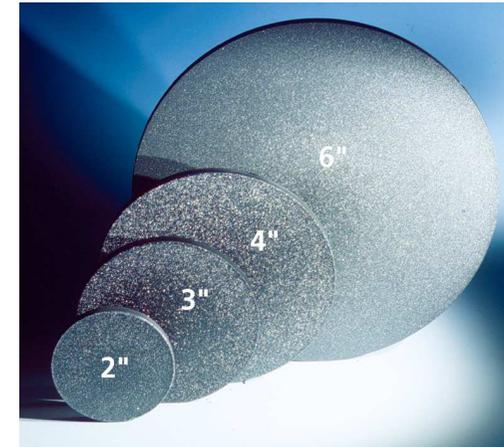
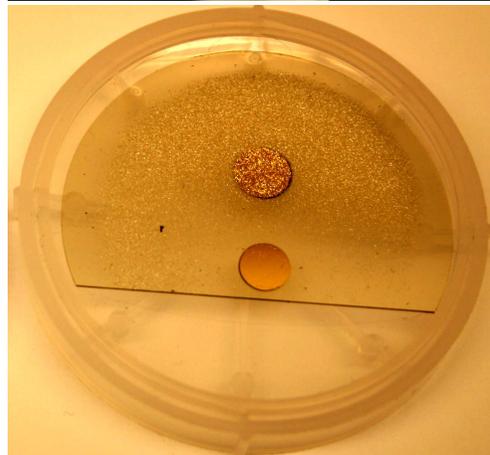


New Manufacturers Developing Detector Grade Diamond



Status:

RD42 has begun working with two companies (Germany, US) to develop detector grade diamond material



◆ First samples from companies show charge collection distance $\sim 100\mu\text{m}$

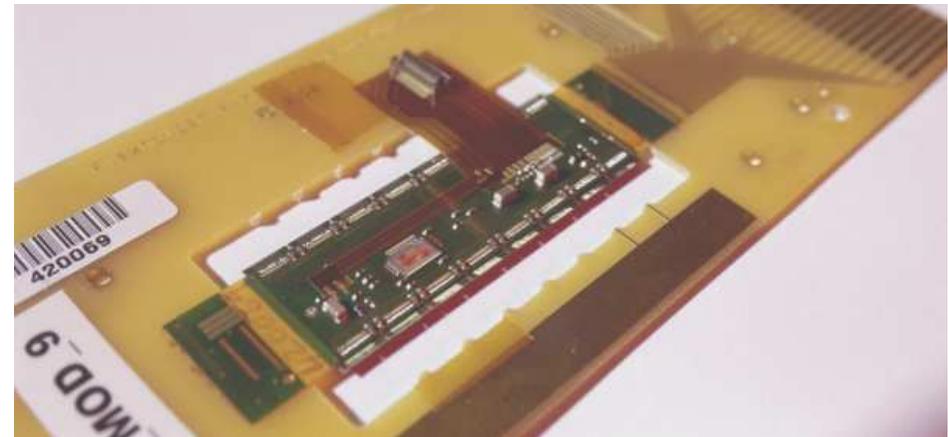
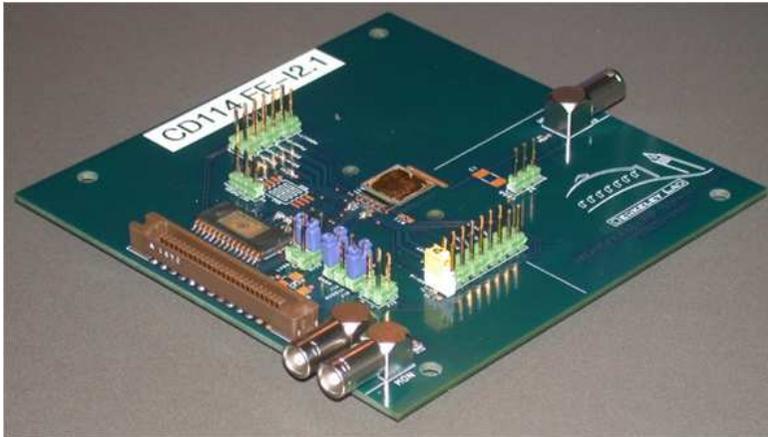


pCVD and scCVD Pixel Detectors

- signal
- noise, threshold, overdrive
- charge sharing, signal over threshold



ATLAS diamond pixel modules



- ❖ Single chip and full modules bump-bonded at IZM (Berlin), constructed and tested in Bonn
- ❖ Operating parameters (FE-I3): Peaking Time 22ns, Noise 140 e , Threshold 1450-1550 e , Threshold Spread 25 e , Overdrive 800 e

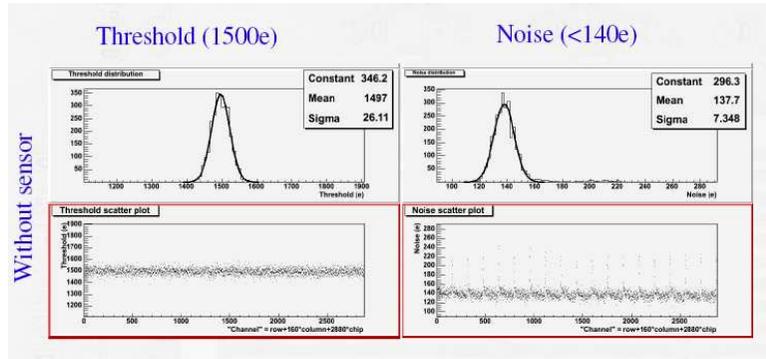


ATLAS Diamond Pixel Detectors



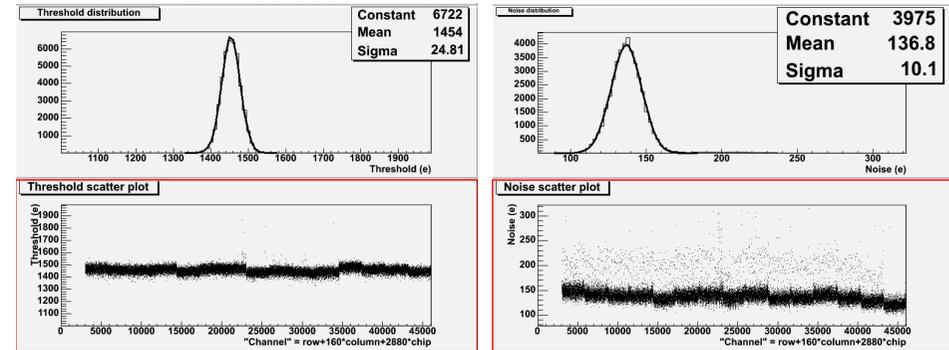
The ATLAS pixel module - Noise, Threshold

Bare Chips

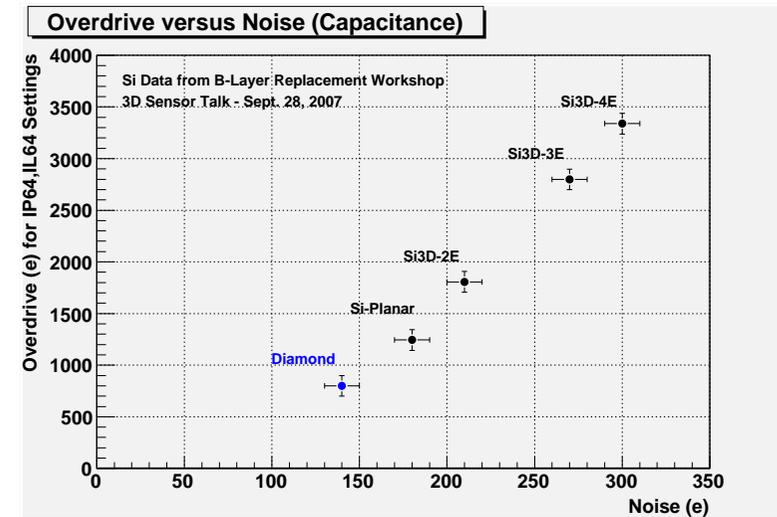
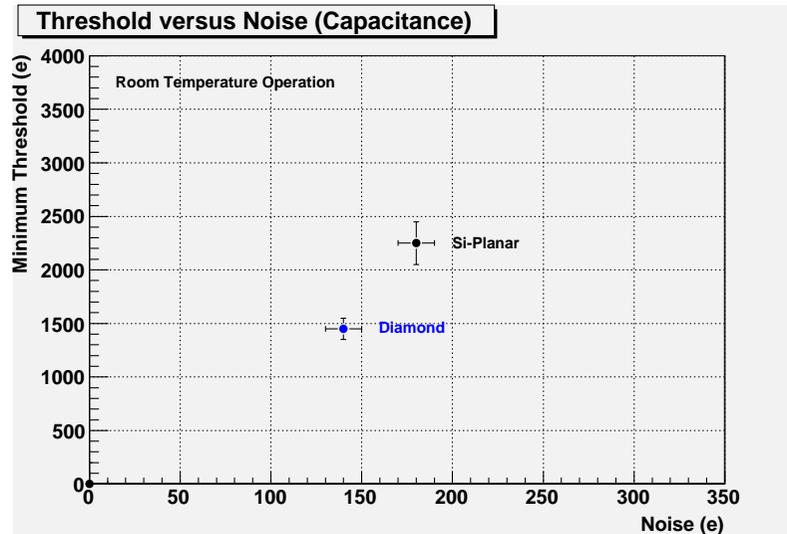


Noise $\sim 140e$, Mean Threshold $1500e$,
Threshold Spread $\sim 25e$.

with Diamond Detector

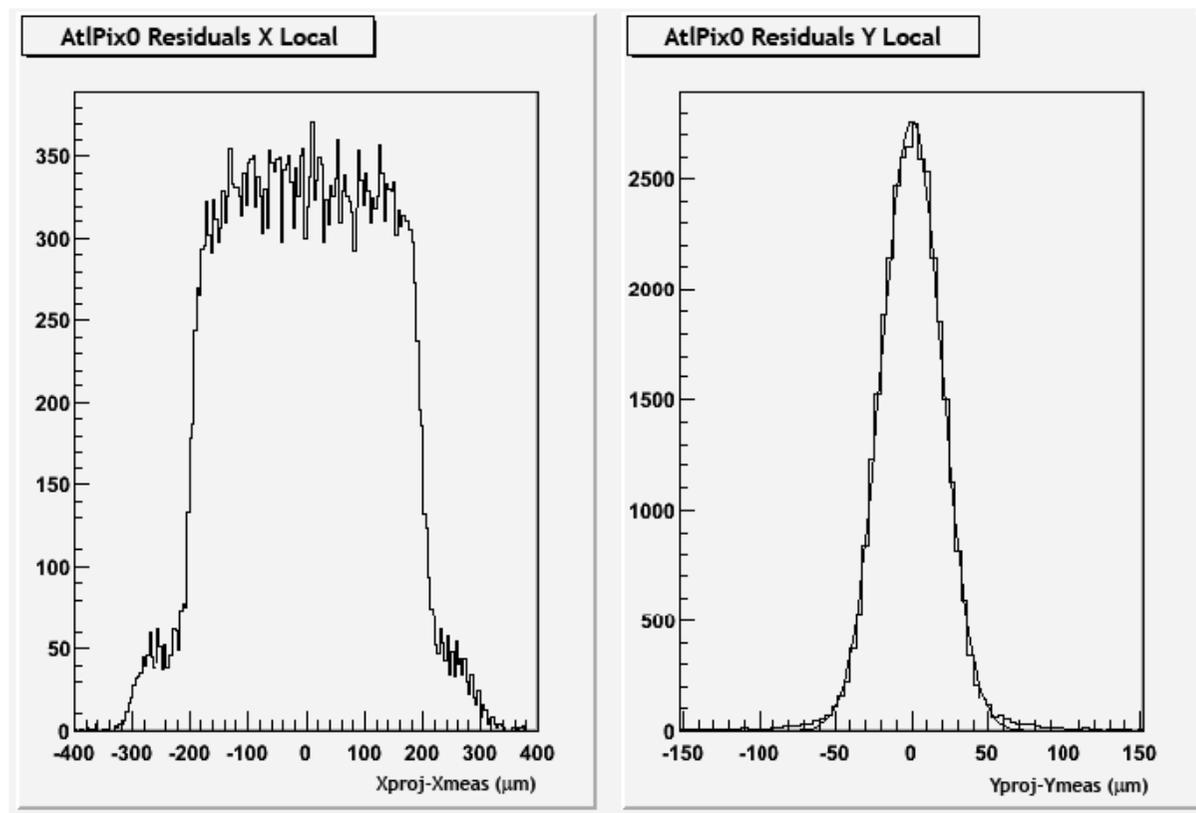


Noise $\sim 137e$, Mean Threshold $1454e$,
Threshold Spread $\sim 25e$.





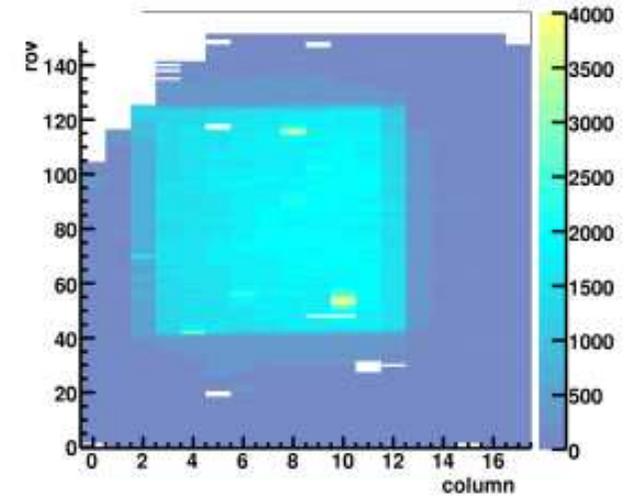
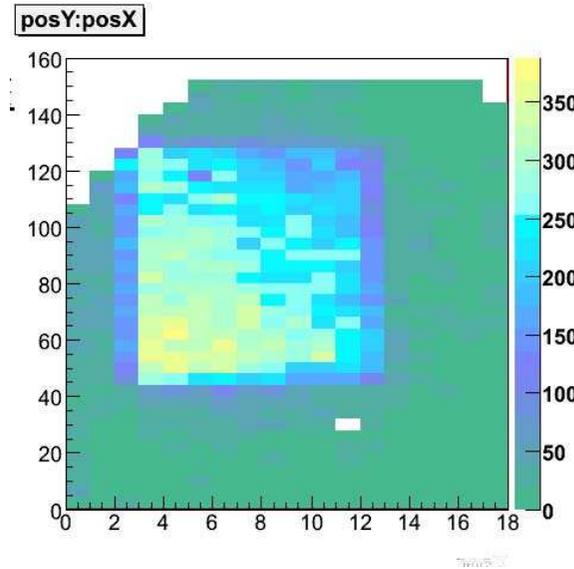
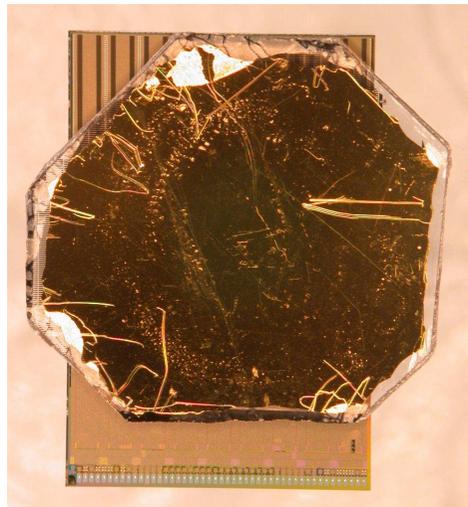
The full ATLAS diamond pixel module - Resolution



- ◆ Excellent correlation with telescope
- ◆ Residual $\sim 18\mu\text{m}$ - remove telescope tracking contribution $\rightarrow 14\mu\text{m}$.



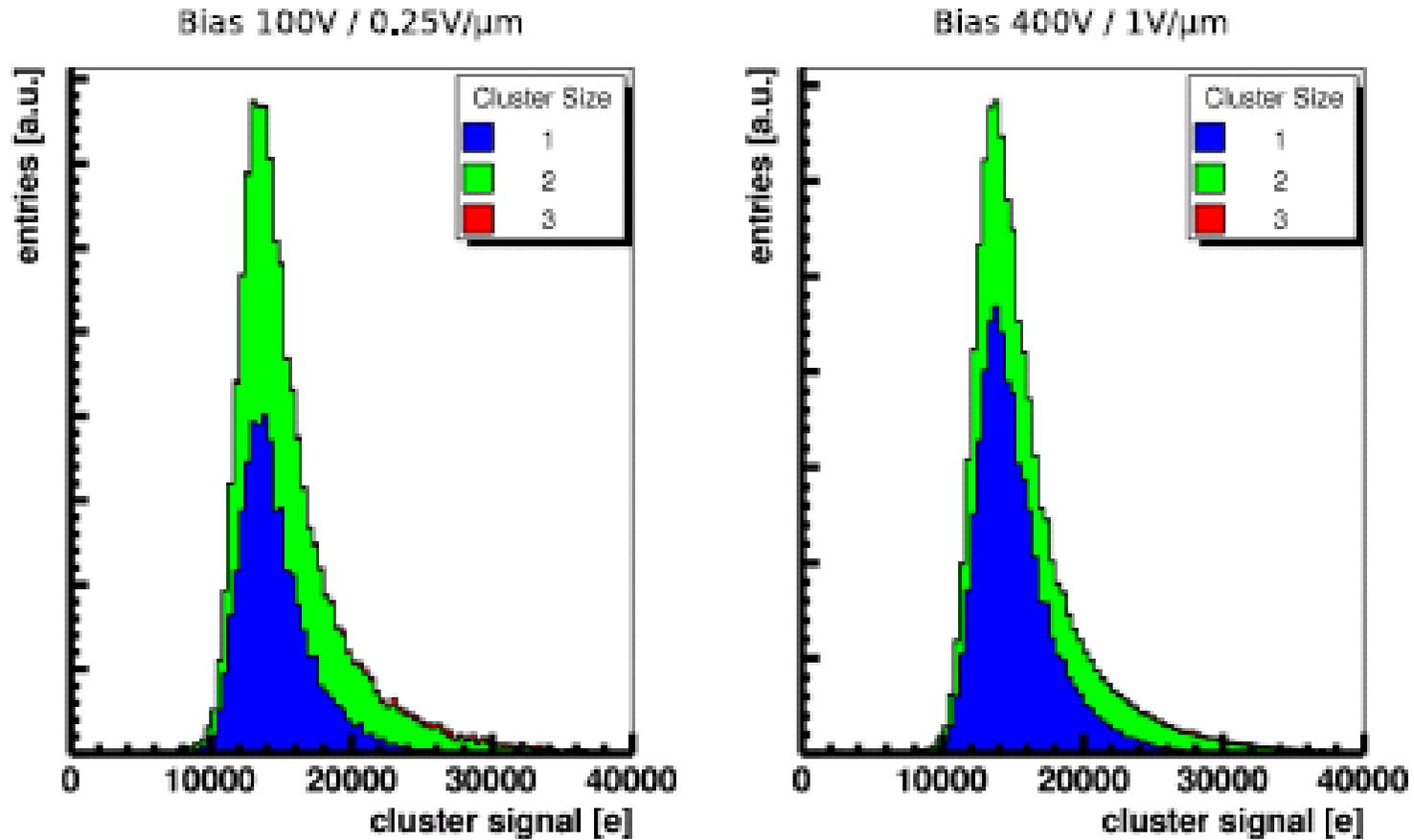
The First scCVD ATLAS diamond pixel detector



- ❖ The hitmap plotted for all scintillation triggers with trigger in telescope.
- ❖ The raw hitmap looks good - ~ 1 dead pixel



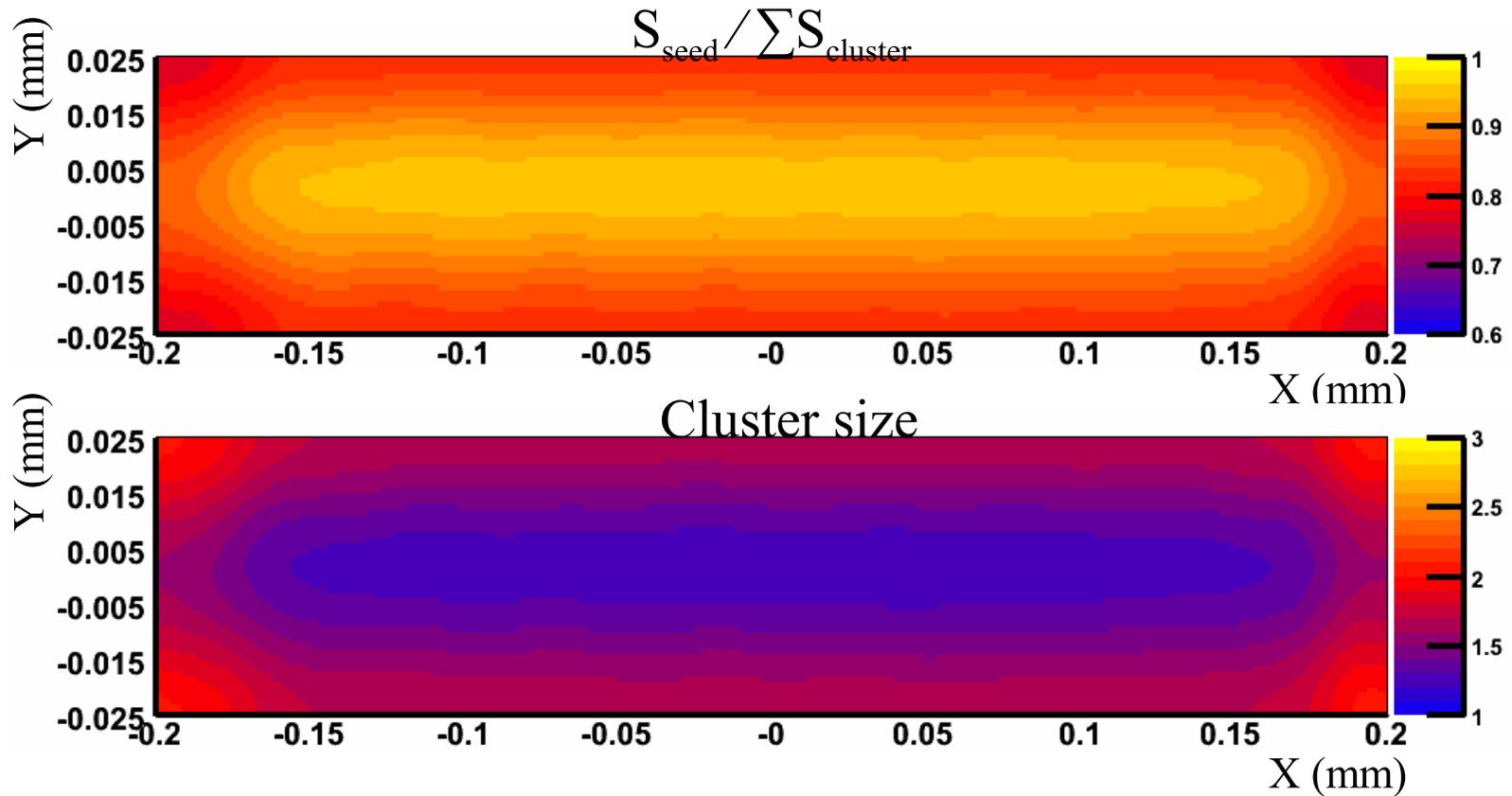
scCVD ATLAS diamond pixel detector - Cluster Signal



◆ As voltage is raised → more 1-hit clusters



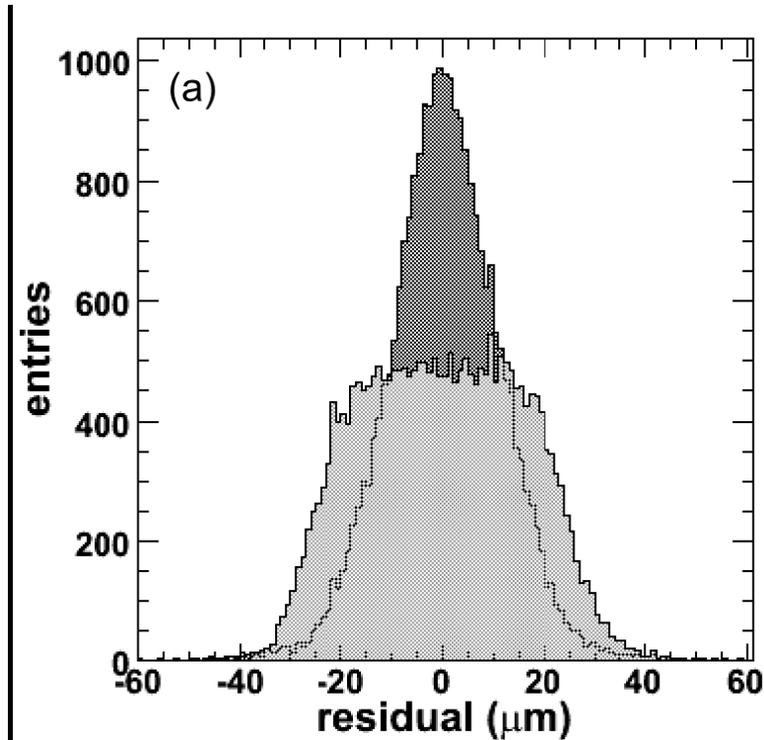
scCVD ATLAS diamond pixel detector - Charge Sharing



- ❖ Charge sharing as expected
- ❖ Cluster signal as expected



scCVD diamond pixel detector - Position Resolution (1-Strip and 2-Strip η)



- ◆ Plot contains all scintillator triggers with “track” trigger in telescope
- ◆ The pixel detector hits correlate well with the telescope hits
- ◆ Residual $\sim 9\mu\text{m}$ (η algorithm) - after removing telescope tracking

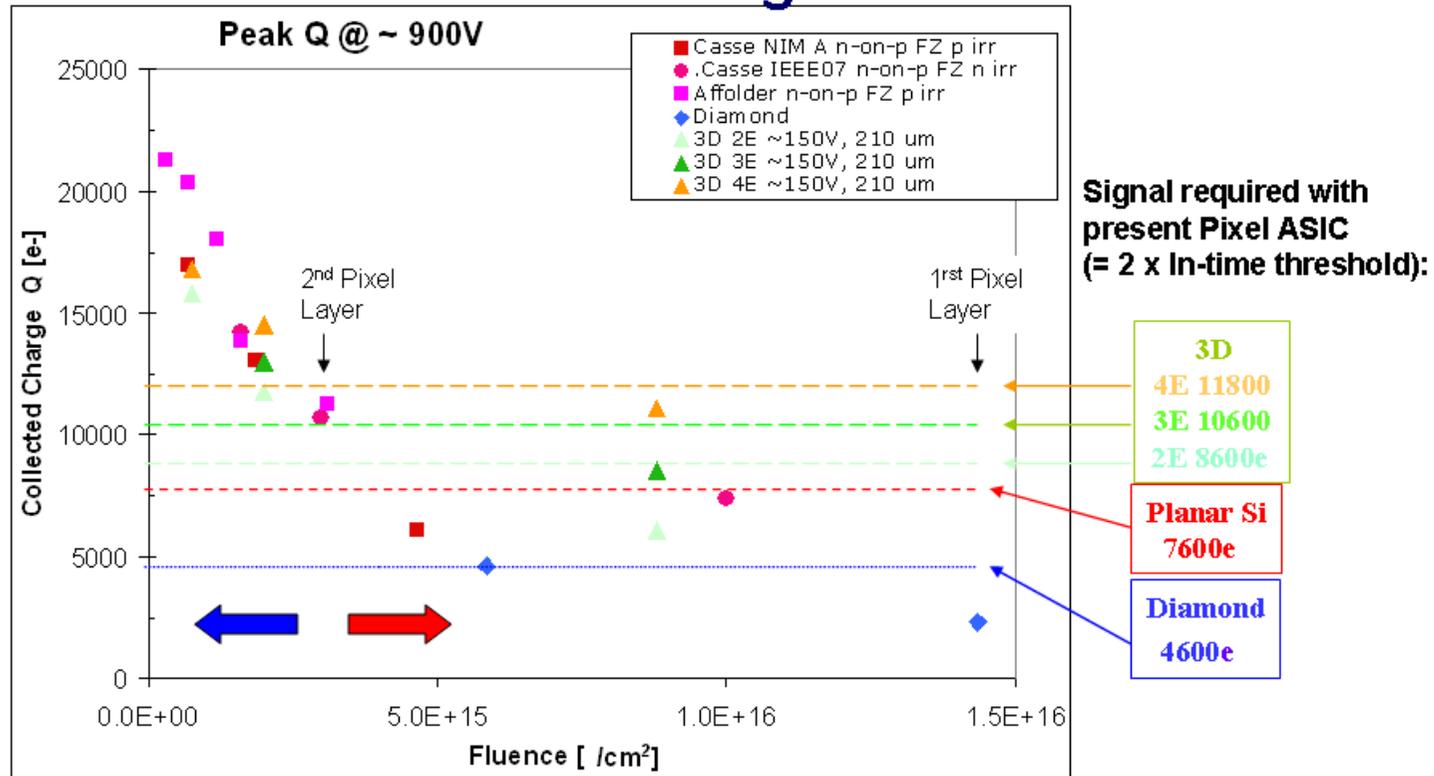


Radiation Hardness Comparison



Signal/2x In-time Threshold (from H. Sadrozinski Jun08 ATLAS talk):

Pixel S/N -> Signal/Threshold



Need to optimize FEE

Marginal performance for innermost Pixel Layer



Plans



On the bases of these results ATLAS officially approved Upgrade R&D on Diamond Pixel Detectors

Proposing Institutes:

- ❖ Carleton University (Canada)
- ❖ University of Toronto (Canada)
- ❖ University of Bonn (Germany)
- ❖ Jožef Stefan Institute (Slovenia)
- ❖ CERN
- ❖ Ohio State University (US)

- ❖ Submitted May 2007
- ❖ Approved Feb 2008
- ❖ Technical Decision 2010

	Diamond Pixel Modules for the High Luminosity ATLAS Inner Detector Upgrade		
	ATLAS Upgrade Document No.	Institute Document No.	Created: 15/05/2007 Modified: 21/12/2007

<p>Abstract</p> <p><i>The goal of this proposal is to construct diamond pixel modules as an option for the ATLAS pixel detector upgrade. This proposal is made possible by progress in three areas: the recent reproducible production of high quality polycrystalline Chemical Vapour Deposition diamond material in wafers, the successful completion and test of the first diamond ATLAS pixel module, and the operation of a diamond after irradiation to 1.8×10^{16} p/cm². In this proposal we outline the results in these three areas and propose a plan to build 5 to 10 ATLAS diamond pixel modules, characterize their properties, test their radiation hardness, explore the cooling advantages made available by the high thermal conductivity of diamond and demonstrate industrial viability of bump-bonding of diamond pixel modules. Based on availability and size polycrystalline Chemical Vapour Deposition diamond has been chosen as the baseline solution. The use of single crystal Chemical Vapour Deposition diamond is reserved as a future option if the manufacturers can attain sizes in the range 16mm x 16mm.</i></p>

Reference → ATU-RD-MN-0012, EDMS ID: 903424



❖ Irradiation of diamond pixel modules at CERN

Done - single chip → 10^{15} p/cm²

Done - full module → 10^{14} p/cm²

In Progress - full module → 10^{15} p/cm²

Status - data being analyzed

❖ Irradiation of pCVD diamonds

Done (Japan) - 1 10^{15} p/cm², 2 10^{16} p/cm²

Done (CERN) - 1 1.8×10^{16} p/cm²

In Progress (CERN) - 1 3×10^{16} p/cm²

Status - data being analyzed, awaiting test beam

❖ Irradiation of scCVD diamonds

Done (CERN) - 1 1.4×10^{15} p/cm²

Done (Japan) - 1 2.5×10^{15} p/cm²

In Progress (CERN) - 1 2.8×10^{15} p/cm²

Status - data being analyzed, awaiting test beam



- ❖ **Move Metalization to Industry**
 - Cleaner facilities
 - Metalization and bumping done at one facility
 - Status - Done

- ❖ **Produce 3-10 Modules in Industry**
 - Evaluate production process
 - Full measure of efficiency, noise, etc.
 - Status - In Progress

- ❖ **Test of Modules**
 - Beam test of production modules
 - Radiation hardness test of production modules
 - Status - In Progress

- ❖ **Construct Pixel Modules with Irradiated Diamond**
 - Status - In Progress

- ❖ **Design Diamond Specific Pixel Module Support**
 - Reduce material, increase heat spreading
 - Status - In Progress



Summary



❖ Further Progress in Charge Collection

pCVD - 300 μm collection distance diamond attained in wafer growth

pCVD - FWHM/MP ~ 0.95 – Working with manufacturers to increase uniformity

scCVD - Full charge collection, fast, large signals, Larger size?

New manufacturers arriving

❖ Radiation Hardness of Diamond Trackers

Using trackers allows a correlation between S/N and Resolution

Dark current decreases with fluence

With protons - pCVD and scCVD have same damage curve

- $E=1\text{V}/\mu\text{m}$: 15% S/N loss at $2.2 \times 10^{15}/\text{cm}^2$, 33% signal at $1.8 \times 10^{16}/\text{cm}^2$

❖ Diamond Pixel Detectors

Successfully tested a complete ATLAS pCVD module and scCVD module

- Excellent correlation for both between telescope and pixel data - stable op
- pCVD \rightarrow digital resolution; scCVD \rightarrow $9\mu\text{m}$ resolution

Diamond R&D Approved by ATLAS for LHC Upgrade R&D